

SANYO Semiconductors DATA SHEET

ECH8411 — General-Purpose Switching Device Applications

Features

· Ultrahigh-speed switching.

• 1.8V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		20	V
Gate-to-Source Voltage	VGSS		±12	V
Drain Current (DC)	۱D		9	А
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	36	А
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm ² X0.8mm)	1.4	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			1.1
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	20			V
Zero-Gate Voltage Drain Current	IDSS	VDS=20V, VGS=0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	0.5		1.3	V
Forward Transfer Admittance	yfs	VDS=10V, ID=4A	7	12		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	ID=4A, VGS=4V		12	16	mΩ
	R _{DS} (on)2	ID=2A, VGS=2.5V		16	23	mΩ
	RDS(on)3	ID=2A, VGS=1.8V		25	36	mΩ
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		1740		pF
Output Capacitance	Coss	VDS=10V, f=1MHz		310		pF
Reverse Transfer Capacitance	Crss	VDS=10V, f=1MHz		290		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		30		ns
Rise Time	tr	See specified Test Circuit.		170		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		240		ns
Fall Time	tf	See specified Test Circuit.		210		ns

Marking : KR

Continued on next page.

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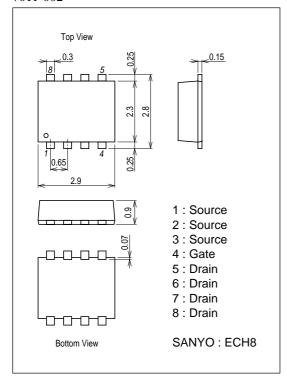
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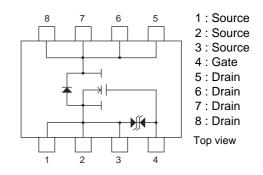
Parameter	Symbol	Conditions	Ratings			Unit
	Symbol		min	typ	max	Onit
Total Gate Charge	Qg	VDS=10V, VGS=4V, ID=9A		21		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =4V, I _D =9A		3.5		nC
Gate-to-Drain "Miller" Charge	Qgd	VDS=10V, VGS=4V, ID=9A		6.2		nC
Diode Forward Voltage	VSD	IS=9A, VGS=0V		0.84	1.2	V

Package Dimensions

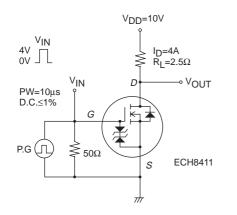
unit : mm 7011-002

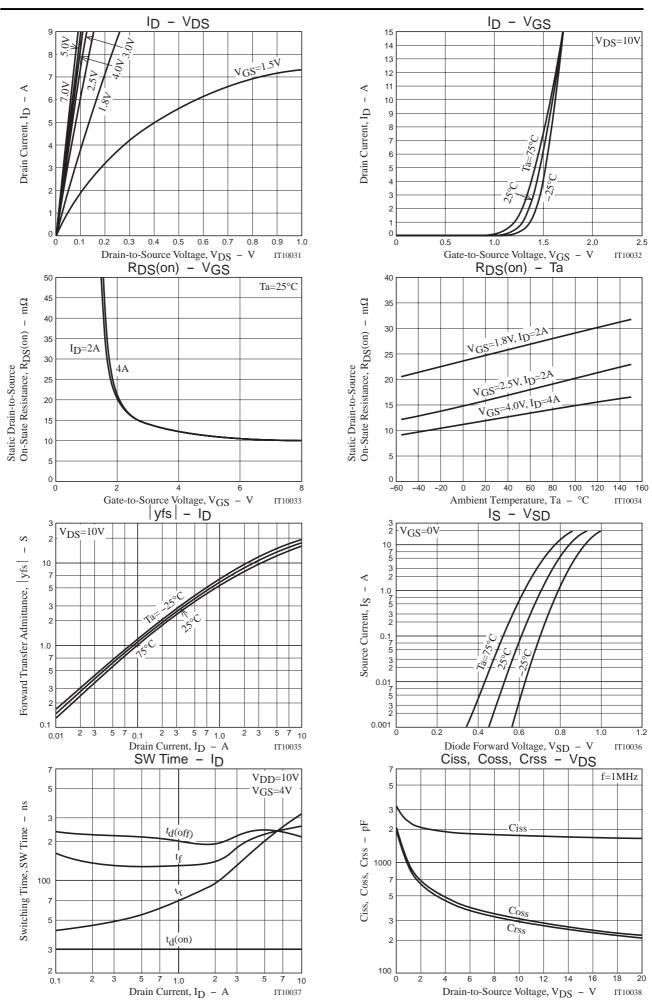


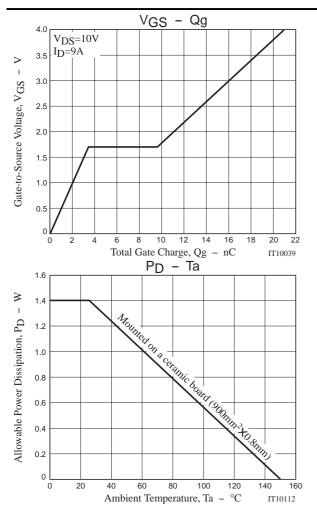
Electrical Connection

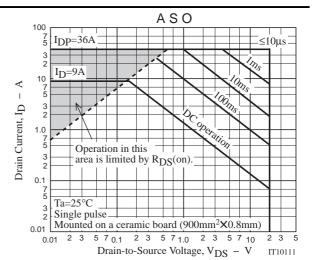


Switching Time Test Circuit









Note on usage : Since the ECH8411 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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